NSN 5962-01-374-2037

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View Online at https://aerobasegroup.com/nsn/5962-01-374-2037
Maximum Power Dissipation Rating:
0.6 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Valve-selecti e/i fscm 70339
Features Provided:
Bipolar and programmed and radiation hardened
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
16 input
Criticality Code Justification:
Feat
Case Outline Source And Designator:
F-9 mil-m-38510
Current Rating Per Characteristic:
-2.00 milliamperes forward current, dc universal and 12.00 milliamperes forward current, dc megawatts
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit memory, 16-input 8-output registered and-or gate array
Voltage Rating And Type Per Characteristic:
-0.5 volts total supply and 7.0 volts total supply
Memory Device Type:
Pal
Hybrid Technology Type:
Monolithic
Special Features:
Nuclear hardness critical item
Test Data Document:
81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-883
standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 printed circuit

Specification Data:

67269 E062 9E1EE06aa government standard and 02640 122a992 10 manufacturers source control

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Departure From Cited Designator:

Altered by programming, testing & marking

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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